Technical Data

# 10 kPa On-Chip Temperature Compensated & Calibrated Silicon Pressure Sensors

The MPX2010/MPXV2010G series silicon piezoresistive pressure sensors provide a very accurate and linear voltage output directly proportional to the applied pressure. These sensors house a single monolithic silicon die with the strain gauge and thin film resistor network integrated on each chip. The sensor is laser trimmed for precise span, offset calibration and temperature compensation.

### **Features**

- Temperature Compensated over 0°C to +85°C
- · Ratiometric to Supply Voltage
- · Differential and Gauge Options

### **Typical Applications**

- · Respiratory Diagnostics
- · Air Movement Control
- Controllers
- Pressure Switching

	ORDERING INFORMATION					
Device Type	Options	Case No.	MPX Series Order No.	Packing Options	Device Marking	
SMALL OUT	SMALL OUTLINE PACKAGE (MPXV2010G SERIES)					
Ported Elements	Gauge, Side Port, SMT	1369	MPXV2010GP	Trays	MPXV2010G	
	Differential, Dual Port, SMT	1351	MPXV2010DP	Trays	MPXV2010G	
UNIBODY PA	ACKAGE (MPX	2010 SERIES	)			
Basic Element	Differential	344	MPX2010D	_	MPX2010D	
Ported Elements	Differential, Dual Port	344C	MPX2010DP	_	MPX2010DP	
	Gauge	344B	MPX2010GP	_	MPX2010GP	
	Gauge, Axial	344E	MPX2010GS	_	MPX2010D	
	Gauge, Axial PC Mount	344F	MPX2010GSX	_	MPX2010D	

# MPX2010 MPXV2010G SERIES

COMPENSATED
PRESSURE SENSOR
0 to 10 kPa (0 to 1.45 psi)
FULL SCALE SPAN: 25 mV

# SMALL OUTLINE PACKAGES

MPXV2010GP CASE 1369-01 MPXV2010DP CASE 1351-01

SMALL OUTLINE PACKAGE PIN NUMBERS						
1	1 GND <sup>(1)</sup> 5 N/C					
2	+V <sub>OUT</sub>	6	N/C			
3	Vs	7	N/C			
4	-V <sub>OUT</sub>	8	N/C			

1. Pin 1 in noted by the notch in the lead.

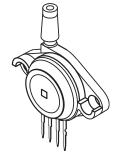
UNIBODY PACKAGE PIN NUMBERS				
1	GND <sup>(1)</sup>	3	V <sub>S</sub>	
2	+V <sub>OUT</sub>	4	–V <sub>OUT</sub>	

1. Pin 1 in noted by the notch in the lead.

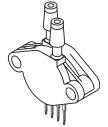
### **UNIBODY PACKAGES**



MPX2010GP CASE 344-15



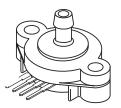
MPX2010GP CASE 344B-01



MPX2010DP CASE 344C-01



MPX2010GS CASE 344E-01



MPX2010GSX CASE 344F-01



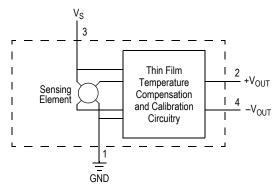


Figure 1. Temperature Compensated and Calibrated Pressure Sensor Schematic

### **VOLTAGE OUTPUT VERSUS APPLIED DIFFERENTIAL PRESSURE**

The output voltage of the differential or gauge sensor increases with increasing pressure applied to the pressure side (P1) relative to the vacuum side (P2). Similarly, output

voltage increases as increasing vacuum is applied to the vacuum side (P2) relative to the pressure side (P1).

Figure 1 shows a block diagram of the internal circuitry on the stand-alone pressure sensor chip.

Table 1. Maximum Ratings<sup>(1)</sup>

Rating	Symbol	Value	Unit
Maximum Pressure (P1 > P2)	P <sub>MAX</sub>	75	kPa
Storage Temperature	T <sub>STG</sub>	-40 to +125	°C
Operating Temperature	T <sub>A</sub>	-40 to +125	°C

<sup>1.</sup> Exposure beyond the specified limits may cause permanent damage or degradation to the device.

**Table 2. Operating Characteristics** ( $V_S = 10 V_{DC}$ ,  $T_A = 25^{\circ}C$  unless otherwise noted, P1 > P2)

Characteristic	Symbol	Min	Тур	Max	Units
Pressure Range <sup>(1)</sup>	P <sub>OP</sub>	0	_	10	kPa
Supply Voltage <sup>(2)</sup>	V <sub>S</sub>	_	10	16	$V_{DC}$
Supply Current	I <sub>O</sub>	_	6.0	_	mAdc
Full Scale Span <sup>(3)</sup>	V <sub>FSS</sub>	24	25	26	mV
Offset <sup>(4)</sup>	V <sub>OFF</sub>	-1.0	_	1.0	mV
Sensitivity	ΔV/ΔΡ	_	2.5	_	mV/kPa
Linearity <sup>(5)</sup>	_	-1.0	_	1.0	%V <sub>FSS</sub>
Pressure Hysteresis <sup>(5)</sup> (0 to 50 kPa)	_	_	±0.1	_	%V <sub>FSS</sub>
Temperature Hysteresis <sup>(5)</sup> (–40°C to +125°C)	_	_	±0.5	_	%V <sub>FSS</sub>
Temperature Effect on Full Scale Span <sup>(5)</sup>	TCV <sub>FSS</sub>	-1.0	_	1.0	%V <sub>FSS</sub>
Temperature Effect on Offset <sup>(5)</sup>	TCV <sub>OFF</sub>	-1.0	_	1.0	mV
Input Impedance	Z <sub>IN</sub>	1000	_	2550	W
Output Impedance	Z <sub>OUT</sub>	1400	_	3000	W
Response Time <sup>(6)</sup> (10% to 90%)	t <sub>R</sub>	_	1.0	_	ms
Warm-Up Time	_	_	2.0	_	ms
Offset Stability <sup>(7)</sup>	_	_	±0.5	_	%V <sub>FSS</sub>

- 1. 1.0 kPa (kiloPascal) equals 0.145 psi.
- 2. Device is ratiometric within this specified excitation range. Operating the device above the specified excitation range may induce additional error due to device self-heating.
- 3. Full Scale Span (V<sub>FSS</sub>) is defined as the algebraic difference between the output voltage at full rated pressure and the output voltage at the minimum related pressure.
- 4. Offset  $(V_{OFF})$  is defined as the output voltage at the minimum rated pressure.
- 5. Accuracy (error budget) consists of the following:
  - Linearity: Output deviation from a straight line relationship with pressure over the specified pressure range.
  - Temperature Hysteresis:Output deviation at any temperature within the operating temperature range, after the temperature is cycled to and from the minimum or maximum operating temperature points, with zero differential pressure applied.
  - Pressure Hysteresis: Output deviation at any pressure within the specified range, when this pressure is cycled to and from the minimum or maximum rated pressure, at 25°C.
  - TcSpan: Output deviation over the temperature range of 0° to 85°C, relative to 25°C.
  - TcOffset: Output deviation with minimum rated pressure applied, over the temperature range of 0° to 85°C, relative to 25°C.
  - Variation from Nominal: The variation from nominal values, for Offset or Full Scale Span, as a percent of V<sub>ESS</sub>, at 25°C.
- 6. Response Time is defined as the time form the incremental change in the output to go from 10% to 90% of its final value when subjected to a specified step change in pressure.
- 7. Offset stability is the product's output deviation when subjected to 1000 hours of Pulsed Pressure, Temperature Cycling with Bias Test.

### ON-CHIP TEMPERATURE COMPENSATION AND CALIBRATION

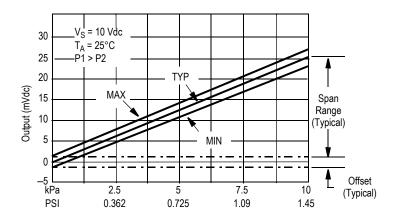


Figure 2. Output vs. Pressure Differential

Figure 2 shows the output characteristics of the MPX2010/MPXV2010G series at 25°C. The output is directly proportional to the differential pressure and is essentially a straight line.

The effects of temperature on full scale span and offset are very small and are shown under Operating Characteristics.

This performance over temperature is achieved by having both the shear stress strain gauge and the thin-film resistor circuitry on the same silicon diaphragm. Each chip is dynamically laser trimmed for precise span and offset calibration and temperature compensation.

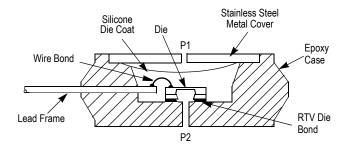


Figure 3. Unibody Package: Cross Sectional Diagram (Not to Scale)

Figure 3 illustrates the differential/gauge die in the basic chip carrier (Case 344). A silicone gel isolates the die surface and wire bonds from the environment, while allowing the pressure signal to be transmitted to the silicon diaphragm.

The MPX2010/MPXV2010G series pressure sensor operating characteristics and internal reliability and

qualification tests are based on use of dry air as the pressure media. Media other than dry air may have adverse effects on sensor performance and long term reliability. Contact the factory for information regarding media compatibility in your application.

### **LINEARITY**

Linearity refers to how well a transducer's output follows the equation:  $V_{out} = V_{off} + \text{sensitivity } \times P$  over the operating pressure range. There are two basic methods for calculating nonlinearity: (1) end point straight line fit (see Figure 4) or (2) a least squares best line fit. While a least squares fit gives the "best case" linearity error (lower numerical value), the calculations required are burdensome.

Conversely, an end point fit will give the "worst case" error (often more desirable in error budget calculations) and the calculations are more straightforward for the user. Freescale's specified pressure sensor linearities are based on the end point straight line method measured at the midrange pressure.

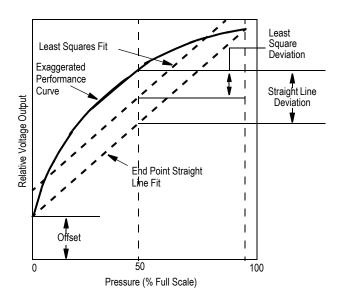


Figure 4. Linearity Specification Comparison

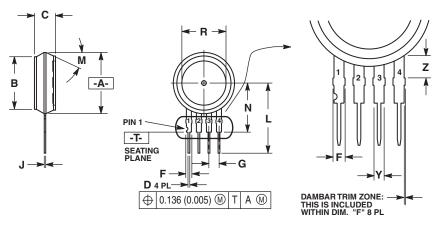
### PRESSURE (P1)/VACUUM (P2) SIDE IDENTIFICATION TABLE

Freescale designates the two sides of the pressure sensor as the Pressure (P1) side and the Vacuum (P2) side. The Pressure (P1) side is the side containing silicone gel which isolates the die from the environment. The Freescale MPX pressure sensor is designed to operate with positive differential pressure applied, P1 > P2.

The Pressure (P1) side may be identified by using the following table.

Table 3. Pressure (P1) Side Delineation

Part Number	Case Type	Pressure (P1) Side Identifier
MPX2010D	344	Stainless Steep Cap
MPX2010DP	344C	Side with Part Marking
MPX2010GP	344B	Side with Port Attached
MPX2010GS	344E	Side with Port Attached
MPX2010GSX	344F	Side with Port Attached
MPXV2010GP	1369	Side with Port Attached
MPXV2010DP	1351	Side with Part Marking

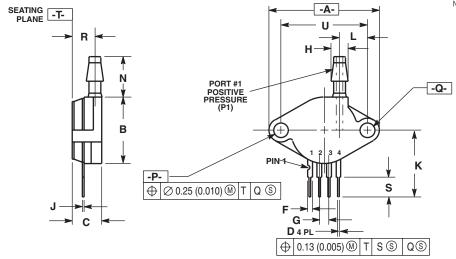


- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: INCH.
- DIMENSION -A- IS INCLUSIVE OF THE MOLD STOP RING. MOLD STOP RING NOT TO EXCEED 16.00 (0.630).

	INCHES		MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.595	0.630	15.11	16.00
В	0.514	0.534	13.06	13.56
O	0.200	0.220	5.08	5.59
D	0.016	0.020	0.41	0.51
F	0.048	0.064	1.22	1.63
G	0.100	BSC	2.54 BSC	
J	0.014	0.016	0.36	0.40
Г	0.695	0.725	17.65	18.42
M	30°	NOM	30° NOM	
N	0.475	0.495	12.07	12.57
R	0.430	0.450	10.92	11.43
Υ	0.048	0.052	1.22	1.32
Z	0.106	0.118	2.68	3.00

- STYLE 1: PIN 1. GROUND 2. + OUTPUT 3. + SUPPLY 4. OUTPUT
- STYLE 2: PIN 1. Vcc 2. SUPPLY 3. + SUPPLY 4. GROUND
- STYLE 3: PIN 1. GND 2. -VOUT 3. VS 4. +VOUT

### **CASE 344-15 ISSUE AA UNIBODY PACKAGE**



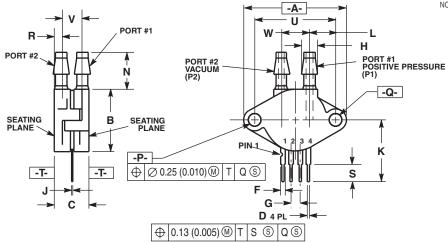
### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INC	HES	MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	1.145	1.175	29.08	29.85
В	0.685	0.715	17.40	18.16
С	0.305	0.325	7.75	8.26
D	0.016	0.020	0.41	0.51
F	0.048	0.064	1.22	1.63
G	0.100	0.100 BSC		BSC
Н	0.182	0.194	4.62	4.93
J	0.014	0.016	0.36	0.41
K	0.695	0.725	17.65	18.42
L	0.290	0.300	7.37	7.62
N	0.420	0.440	10.67	11.18
Р	0.153	0.159	3.89	4.04
Q	0.153	0.159	3.89	4.04
R	0.230	0.250	5.84	6.35
S	0.220	0.240	5.59	6.10
U	0.910	) BSC	23.11	BSC

STYLE 1: PIN 1. GROUND 2. + OUTPUT 3. + SUPPLY 4. - OUTPUT

**CASE 344B-01 ISSUE B UNIBODY PACKAGE** 



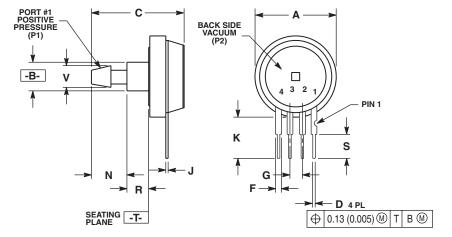
### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	1.145	1.175	29.08	29.85
В	0.685	0.715	17.40	18.16
С	0.405	0.435	10.29	11.05
D	0.016	0.020	0.41	0.51
F	0.048	0.064	1.22	1.63
G	0.100	BSC	2.54 BSC	
Н	0.182	0.194	4.62	4.93
J	0.014	0.016	0.36	0.41
K	0.695	0.725	17.65	18.42
L	0.290	0.300	7.37	7.62
N	0.420	0.440	10.67	11.18
Р	0.153	0.159	3.89	4.04
Q	0.153	0.159	3.89	4.04
R	0.063	0.083	1.60	2.11
S	0.220	0.240	5.59	6.10
U	0.910	BSC	23.1	1 BSC
٧	0.248	0.278	6.30	7.06
W	0.310	0.330	7.87	8.38

STYLE 1: PIN 1. GROUND 2. + OUTPUT 3. + SUPPLY 4. - OUTPUT

### **CASE 344C-01 ISSUE B UNIBODY PACKAGE**



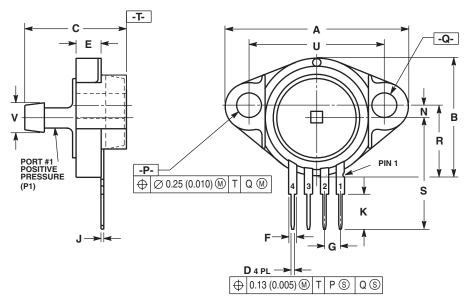
### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.690	0.720	17.53	18.28
В	0.245	0.255	6.22	6.48
С	0.780	0.820	19.81	20.82
D	0.016	0.020	0.41	0.51
F	0.048	0.064	1.22	1.63
G	0.100	BSC	2.54 BSC	
J	0.014	0.016	0.36	0.41
K	0.345	0.375	8.76	9.53
N	0.300	0.310	7.62	7.87
R	0.178	0.186	4.52	4.72
S	0.220	0.240	5.59	6.10
٧	0.182	0.194	4.62	4.93

STYLE 1: PIN 1. GROUND 2. + OUTPUT 3. + SUPPLY 4. - OUTPUT

**CASE 344E-01 ISSUE B UNIBODY PACKAGE** 

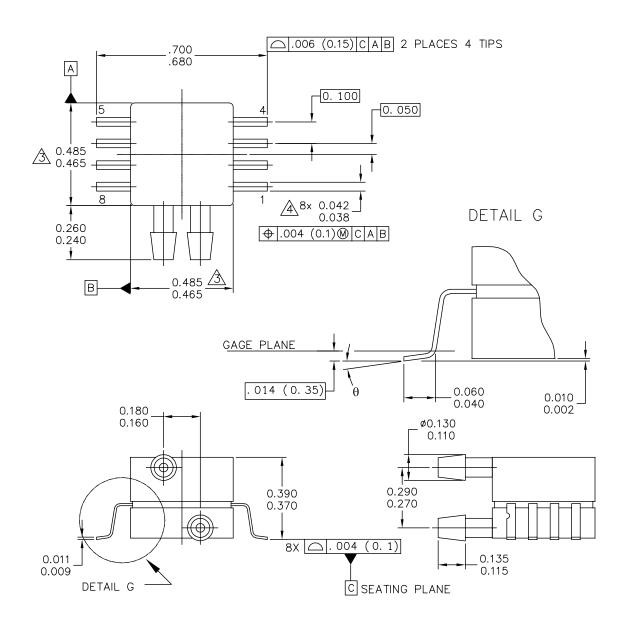


- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.

	INC	HES	MILLIN	ETERS
DIM	MIN	MAX	MIN	MAX
Α	1.080	1.120	27.43	28.45
В	0.740	0.760	18.80	19.30
С	0.630	0.650	16.00	16.51
D	0.016	0.020	0.41	0.51
Е	0.160	0.180	4.06	4.57
F	0.048	0.064	1.22	1.63
G	0.100	BSC	2.54 BSC	
J	0.014	0.016	0.36	0.41
K	0.220	0.240	5.59	6.10
Ν	0.070	0.080	1.78	2.03
Р	0.150	0.160	3.81	4.06
Q	0.150	0.160	3.81	4.06
R	0.440	0.460	11.18	11.68
S	0.695	0.725	17.65	18.42
U	0.840	0.860	21.34	21.84
٧	0.182	0.194	4.62	4.92

STYLE 1: PIN 1. GROUND 2. V (+) OUT 3. V SUPPLY 4. V (-) OUT

**CASE 344F-01 ISSUE B UNIBODY PACKAGE** 



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8 LD SNSR, DUAL	PORT	CASE NUMBER	2: 1351–01	27 JUL 2005
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PAGE 1 OF 2

### CASE1351-01 ISSUE A SMALL OUTLINE PACKAGE

### NOTES:

- 1. CONTROLLING DIMENSION: INCH
- 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
- DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PPROTRUSIONS.

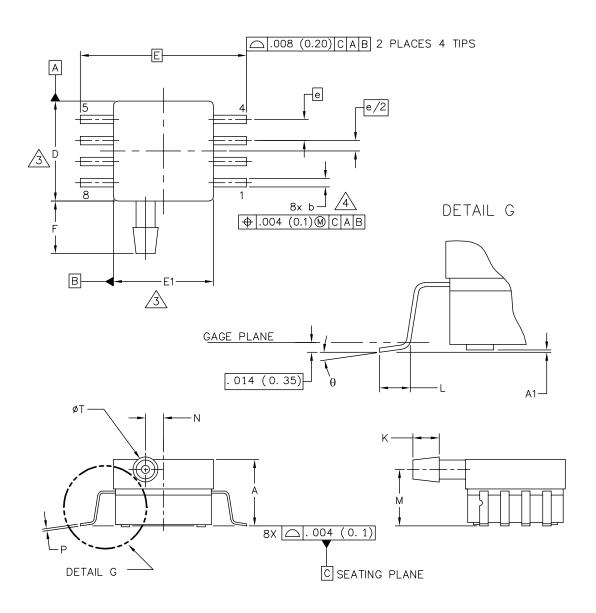
  MOLD FLASH AND PROTRUSIONS SHALL NOT EXCEED .006 PER SIDE.
- DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE .008 MAXIMUM.

		STYLE 2:		
1:	GND	PIN	1:	N/C
2:	+Vout	PIN	2:	٧s
3:	٧s	PIN	3:	GND
4:	−Vout	PIN	4:	Vout
5:	N/C	PIN	5:	N/C
6:	N/C	PIN	6:	N/C
7:	N/C	PIN	7:	N/C
8:	N/C	PIN	8:	N/C
	1: 2: 3: 4: 5: 6: 7:	1: GND 2: +Vout 3: Vs 4: -Vout 5: N/C 6: N/C 7: N/C 8: N/C	1: GND PIN 2: +Vout PIN 3: Vs PIN 4: -Vout PIN 5: N/C PIN 6: N/C PIN 7: N/C PIN	1: GND PIN 1: 2: +Vout PIN 2: 3: Vs PIN 3: 4: -Vout PIN 4: 5: N/C PIN 5: 6: N/C PIN 6: 7: N/C PIN 7:

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PAGE 1 OF 2

### CASE 1369-01 ISSUE B SMALL OUTLINE PACKAGE

### NOTES:

- 1. CONTROLLING DIMENSION: INCH
- 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
- △ DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PPROTRUSIONS.

  MOLD FLASH AND PROTRUSIONS SHALL NOT EXCEED .006 (0.152) PER SIDE.
- A DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE .008 (0.203) MAXIMUM.

	INCHES		MILLIMETERS			INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX	DIM	MIN	MAX	MIN	MAX
A	. 300	. 330	7. 11	7. 62	θ	0.	7 <b>°</b>	0°	7 <b>°</b>
A 1	. 002	. 010	0. 05	0. 25	-				
b	. 038	. 042	0. 96	1. 07	_				
D	. 465	. 485	11. 81	12. 32	-				
E .717 BSC		18	.21 BSC	_					
E1	. 465	. 485	11. 81	12. 32	_				
e	. 100	BSC	2. 54 BSC		_				
F	. 245	. 255	6. 22	6. 47	_				
K	. 120	. 130	3. 05	3. 30	_				
L	. 061	. 071	1. 55	1. 80	_				
М	. 270	. 290	6. 86	7. 36	_				
N	. 080	. 090	2. 03	2. 28	_				
Р	. 009	. 011	0. 23	0. 28	_				
Т	. 115	. 125	2. 92	3. 17	_				
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PAGE 2 OF 2

### CASE 1369-01 ISSUE B SMALL OUTLINE PACKAGE

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